

## **Defect and Material Characterisation Discussion**

**3 more talks on Wednesday on defect and material characterisation in Si**

**RD50 Meeting in Hamburg on August 23-24 on Defect and Material Characterisation**

**Main Topics of discussion:**

- **X and I /  $V_2O$  or  $V_2O_2$  defects: further progress**
- **Thermal Donors activation during processing of p-type MCz**
  - **Differences in n and p ???**
- **Donor production during irradiation**
  - **Linked to  $O_2$ ??**
- **Reverse Annealing link to defect**
  - **W-line link???**
- **Clusters in hadron irradiated silicon**
- **Defects and trapping mechanisms**
  - **Linked to clusters**
- **Impurities H, Li**

**Further discussions on Hamburg meeting**